

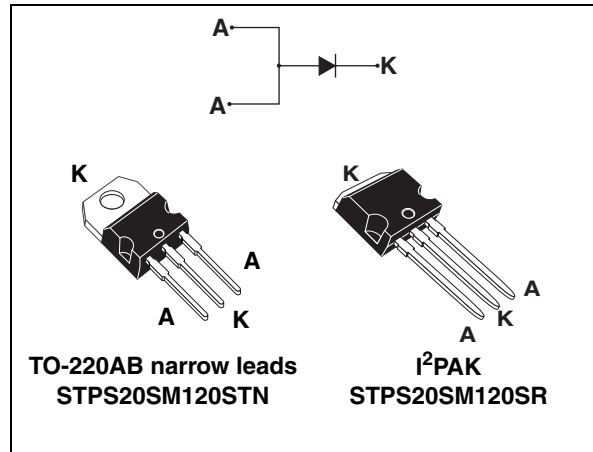
### Features

- High current capability
- Avalanche rated
- Low forward voltage drop
- High frequency operation

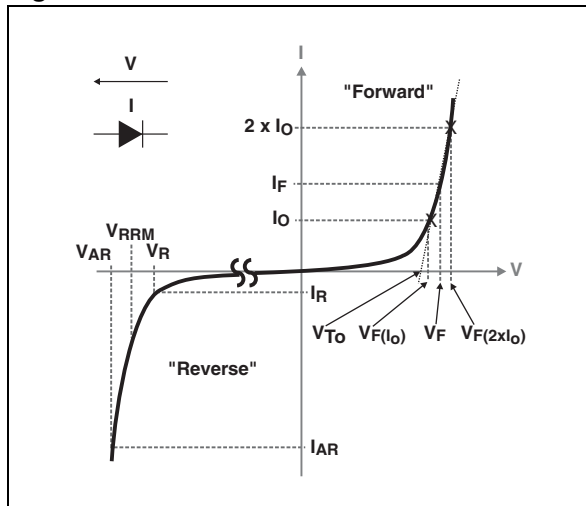
### Description

This Schottky diode is suited for high frequency switch mode power supply.

Packaged in TO-220AB narrow leads and I<sup>2</sup>PAK, this device is intended to be used in notebook, game station and desktop adapters, providing in these applications a good efficiency at both low and high load.



**Figure 1. Electrical characteristics<sup>(a)</sup>**



**Table 1. Device summary**

Symbol	Value
$I_{F(AV)}$	20 A
$V_{RRM}$	120 V
$V_F$ (typ)	0.49 V
$T_j$ (max)	150 °C

- a.  $V_{ARM}$  and  $I_{ARM}$  must respect the reverse safe operating area defined in [Figure 9](#).  $V_{AR}$  and  $I_{AR}$  are pulse measurements ( $t_p < 10 \mu s$ ).  $V_R$ ,  $I_R$ ,  $V_{RRM}$  and  $V_F$  are static characteristics

# 1 Characteristics

**Table 2. Absolute ratings (limiting values with terminals 1 and 3 short circuited at  $T_{amb} = 25\text{ °C}$ , unless otherwise specified)**

Symbol	Parameter	Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	120	V
$I_{F(RMS)}$	Forward rms current	50	A
$I_{F(AV)}$	Average forward current, $\delta = 0.5$	$T_c = 120\text{ °C}$	A
$I_{FSM}$	Surge non repetitive forward current	$t_p = 10\text{ ms sinusoidal}, T_c = 25\text{ °C}$	A
$P_{ARM}^{(1)}$	Repetitive peak avalanche power	$T_j = 125\text{ °C}, t_p = 10\text{ }\mu\text{s}$	W
$V_{ARM}^{(2)}$	Maximum repetitive peak avalanche voltage	$t_p < 10\text{ }\mu\text{s}, T_j < 125\text{ °C}, I_{AR} < 6\text{ A}$	V
$V_{ASM}^{(2)}$	Maximum single-pulse peak avalanche voltage	$t_p < 10\text{ }\mu\text{s}, T_j < 125\text{ °C}, I_{AR} < 6\text{ A}$	V
$T_{stg}$	Storage temperature range	-65 to +175	°C
$T_j$	Maximum operating junction temperature <sup>(3)</sup>	150	°C

1. For pulse time duration deratings, please refer to [Figure 4](#). More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the STMicroelectronics Application notes AN1768, "Admissible avalanche power of schottky diodes" and AN2025, "Converter improvement using Schottky rectifier avalanche specification".

2. See [Figure 9](#)

3.  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  condition to avoid thermal runaway for a diode on its own heatsink

**Table 3. Thermal resistance**

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case	1.55	°C/W

**Table 4. Static electrical characteristics (terminals 1 and 3 short circuited)**

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ }^{\circ}\text{C}$	$V_R = V_{RRM}$	-	40	210	$\mu\text{A}$
		$T_j = 125\text{ }^{\circ}\text{C}$		-	15	40	mA
$V_F^{(2)}$	Forward voltage drop	$T_j = 125\text{ }^{\circ}\text{C}$	$I_F = 5\text{ A}$	-	0.49	0.54	V
		$T_j = 25\text{ }^{\circ}\text{C}$	$I_F = 10\text{ A}$	-		0.75	
		$T_j = 125\text{ }^{\circ}\text{C}$		-	0.57	0.62	
		$T_j = 25\text{ }^{\circ}\text{C}$	$I_F = 20\text{ A}$	-		0.89	
		$T_j = 125\text{ }^{\circ}\text{C}$		-	0.65	0.72	

1. Pulse test:  $t_p = 5\text{ ms}$ ,  $\delta < 2\%$

2. Pulse test:  $t_p = 380\text{ }\mu\text{s}$ ,  $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.56 \times I_{F(AV)} + 0.008 \times I_{F(RMS)}^2$$

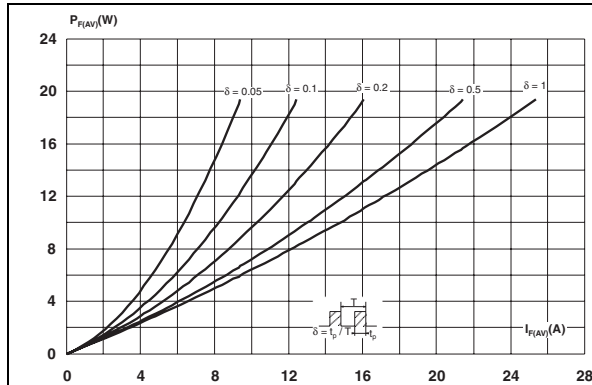
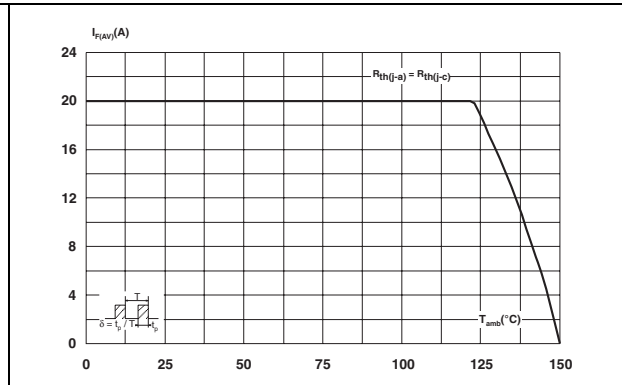
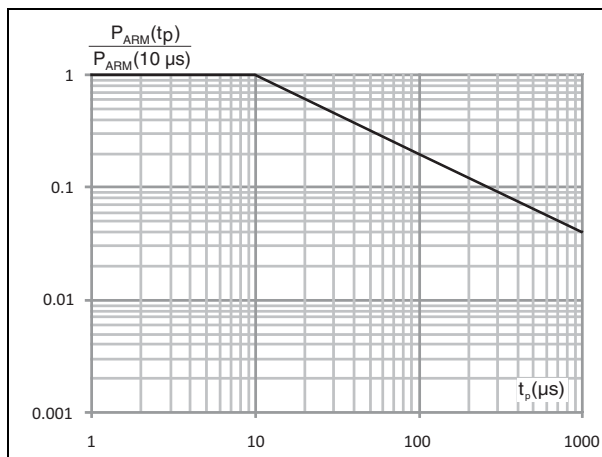
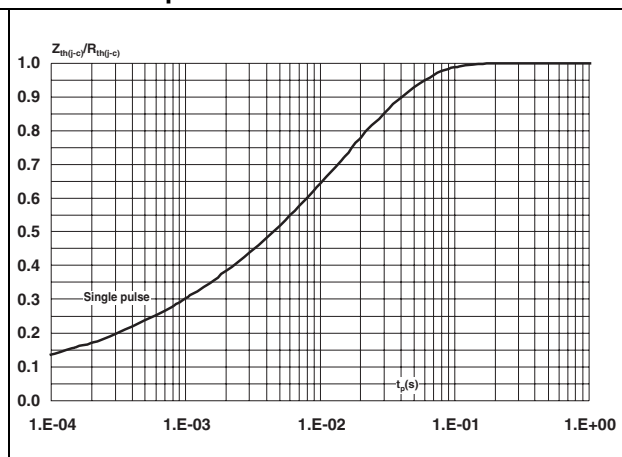
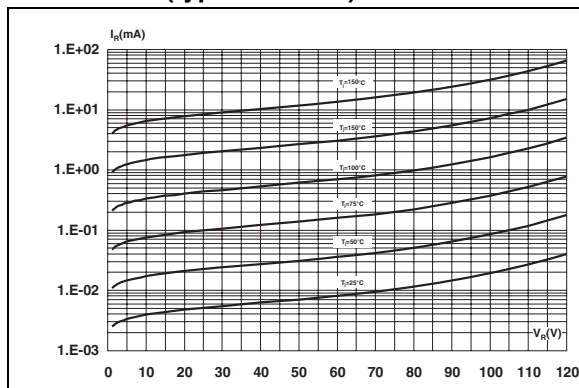
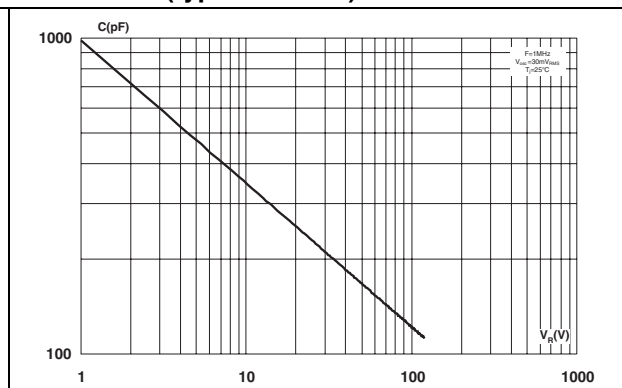
**Figure 2. Average forward power dissipation versus average forward current****Figure 3. Average forward current versus ambient temperature ( $\delta = 0.5$ )****Figure 4. Normalized avalanche power derating versus pulse duration****Figure 5. Relative variation of thermal impedance junction to case versus pulse duration****Figure 6. Reverse leakage current versus reverse voltage applied (typical values)****Figure 7. Junction capacitance versus reverse voltage applied (typical values)**

Figure 8. Forward voltage drop versus forward current

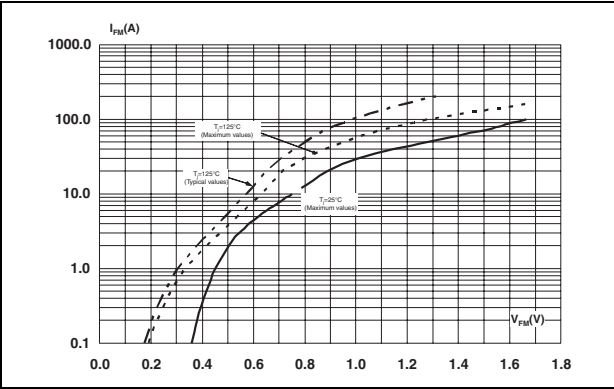
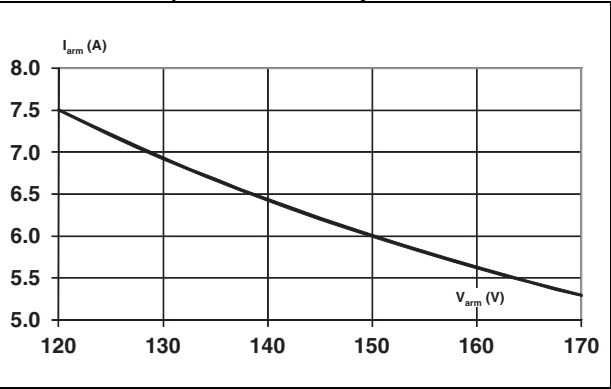


Figure 9. Reverse safe operating area ( $t_p < 10\ \mu\text{s}$  and  $T_j < 125^\circ\text{C}$ )



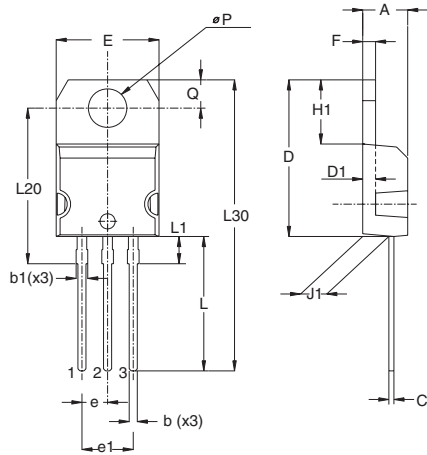
## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

**Table 5. TO-220AB narrow leads dimensions**

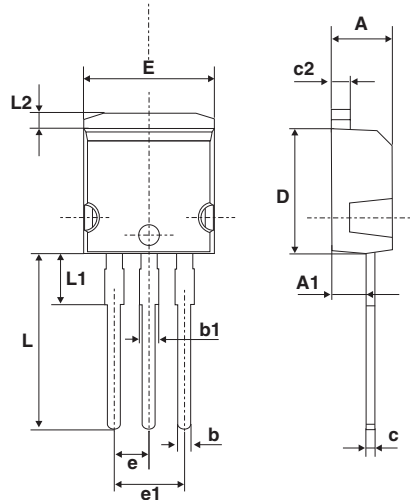
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.17		0.18
b	0.61		0.88	0.024		0.034
b1	0.95		1.20	0.037		0.047
c	0.48		0.70	0.019		0.027
D	15.25		15.75	0.60		0.62
D1	1.27			0.05		
E	10.00		10.40	0.39		0.41
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.19		0.20
F	1.23		1.32	0.048		0.052
H1	6.20		6.60	0.24		0.26
J1	2.40		2.72	0.095		0.107
L	13.00		14.00	0.51		0.55
L1	2.60		2.90	0.102		0.114
L20	15.40			0.61		
L30	28.90			1.14		
ØP	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



Devices in I<sup>2</sup>PAK with nickel-plated back frame must NOT be mounted by frame soldering like SMDs. Such devices are intended to be through-hole mounted ONLY and in no circumstances shall ST be held liable for any lack of performance or damage arising out of soldering of nickel-plated back frames.

Table 6. I<sup>2</sup>PAK dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.40	2.72	0.094	0.107
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.044	0.067
c	0.49	0.70	0.019	0.028
c2	1.23	1.32	0.048	0.052
D	8.95	9.35	0.352	0.368
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
E	10	10.40	0.394	0.409
L	13	14	0.512	0.551
L1	3.50	3.93	0.138	0.155
L2	1.27	1.40	0.050	0.055



### 3 Ordering information

**Table 7. Ordering information**

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS20SM120SR	PS20SM120SR	I <sup>2</sup> PAK	1.49 g	50	Tube
STPS20SM120STN	PS20SM120STN	TO-220AB narrow leads	1.9 g	50	Tube

### 4 Revision history

**Table 8. Document revision history**

Date	Revision	Changes
02-Apr-2012	1	First issue.

**Please Read Carefully:**

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

**UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.**

**UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.**

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2012 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

[www.st.com](http://www.st.com)